

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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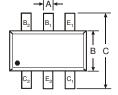
DUAL NPN SMALL SIGNAL SURFACE MOUNT TRANSISTOR

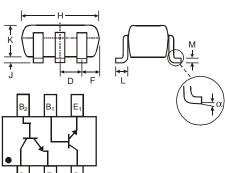
Features

- Epitaxial Planar Die Construction
- Complementary PNP Type Available (IMT4)
- Small Surface Mount Package
- Lead Free/RoHS Compliant (Note 3)
- "Green" Device, Note 4 and 5

Mechanical Data

- Case: SOT-26
- Case Material: Molded Plastic, "Green" Molding Compound, Note 5. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: See Diagram
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Copper leadframe).
- Marking Information: KX8, See Page 3
- Ordering & Date Code Information: See Page 3
- Weight: 0.016 grams (approximate)





	SOT	Γ-26		
Dim	Min	Max	Тур	
A	0.35	0.50	0.38	
В	1.50	1.70	1.60	
C	2.70	3.00	2.80	
D	_		0.95	
F	_		0.55	
Н	2.90	3.10	3.00	
J	0.013	0.10	0.05	
K	1.00	1.30	1.10	
L	0.35	0.55	0.40	
М	0.10	0.20	0.15	
α	0°	8°		
All C	Dimens	ions in	mm	

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	120	V
Collector-Emitter Voltage	V _{CEO}	120	V
Emitter-Base Voltage	V _{EBO}	5.0	V
Collector Current - Continuous	I _C	50	mA
Power Dissipation (Note 1)	P _d	300	mW
Thermal Resistance, Junction to Ambient (Note 1)	$R_{ heta JA}$	417	°C/W
Operating and Storage Temperature Range	T _i , T _{STG}	-55 to +150	°C

Electrical Characteristics @TA = 25°C unless otherwise specified

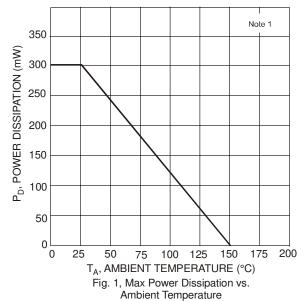
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 2)						
Collector-Base Breakdown Voltage	V _{(BR)CBO}	120	_	_	V	$I_C = 50\mu A$
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	120	_	_	V	I _C = 1.0mA
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	5.0	_	_	V	$I_E = 50\mu A$
Collector Cutoff Current	I _{CBO}	_	_	0.5	μΑ	V _{CB} = 100V
Emitter Cutoff Current	I _{EBO}	_	_	0.5	μΑ	$V_{EB} = 4.0V$
ON CHARACTERISTICS (Note 2)						
DC Current Gain	h _{FE}	180	_	820	_	$I_C = 2.0 \text{mA}, V_{CE} = 6.0 \text{V}$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	_	0.5	V	$I_C = 10 \text{mA}, I_B = 1.0 \text{mA}$
SMALL SIGNAL CHARACTERISTICS						
Current Gain-Bandwidth Product	f _T	_	140	_	MHz	$V_{CE} = 12V, I_{C} = 2.0 \text{mA},$ f = 100MHz

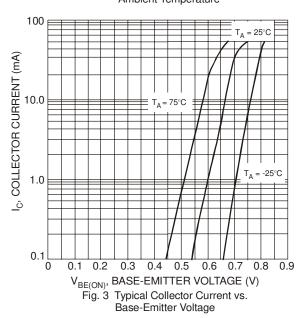
Notes:

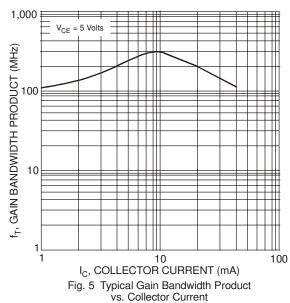
- 1. Device mounted on FR-5 PCB 1.0 x 0.75 x 0.062 inch pad layout as shown on Diodes Inc. suggested pad layout AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf. 200mW per element must not be exceeded.
- 2. Short duration pulse test used to minimize self-heating effect.
- 3. No purposefully added lead.
- 4. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- 5. Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

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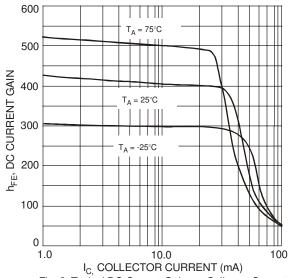


Fig. 2 Typical DC Current Gain vs. Collector Current

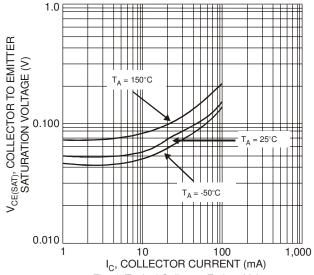
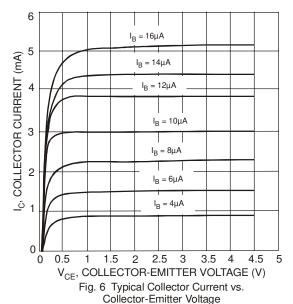


Fig. 4 Typical Collector-Emitter Voltage vs. Collector Current



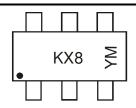


Ordering Information (Note 5 & 6)

Device	Packaging	Shipping
IMX8-7-F	SOT-26	3000/Tape & Reel

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



KX8 = Product Type Marking Code YM = Date Code Marking Y = Year ex: T = 2006 M = Month ex: 9 = September

Date Code Key

Year	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	N	Р	R	S	Т	U	V	W	Χ	Υ	Z

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

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